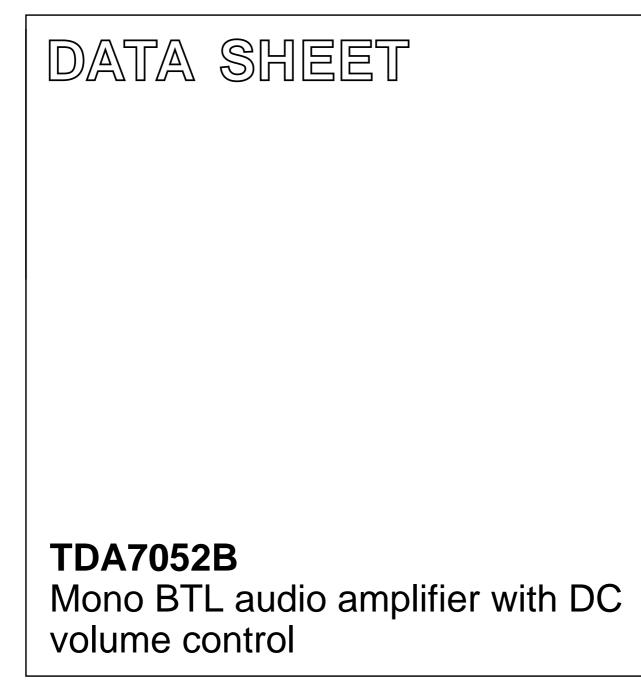
INTEGRATED CIRCUITS



Preliminary specification Supersedes data of July 1994 File under Integrated Circuits, IC01 1996 May 28



### TDA7052B

### FEATURES

- DC volume control
- Few external components
- Mute mode
- Thermal protection
- Short-circuit proof
- No switch-on and switch-off clicks
- Good overall stability
- Low power consumption
- Low HF radiation
- ESD protected on all pins.

### QUICK REFERENCE DATA

### **GENERAL DESCRIPTION**

The TDA7052B and TDA7052BT are 1 W and 0.5 W mono Bridge-Tied Load (BTL) output amplifiers with DC volume control.

They have been designed for use in TV and monitors, but are also suitable for use in battery-fed portable recorders and radios.

A Missing Current Limiter (MCL) is built in. The MCL circuit is activated when the difference in current between the output terminal of each amplifier exceeds 100 mA (300 mA typ.). This level of 100 mA allows for headphone applications (single-ended).

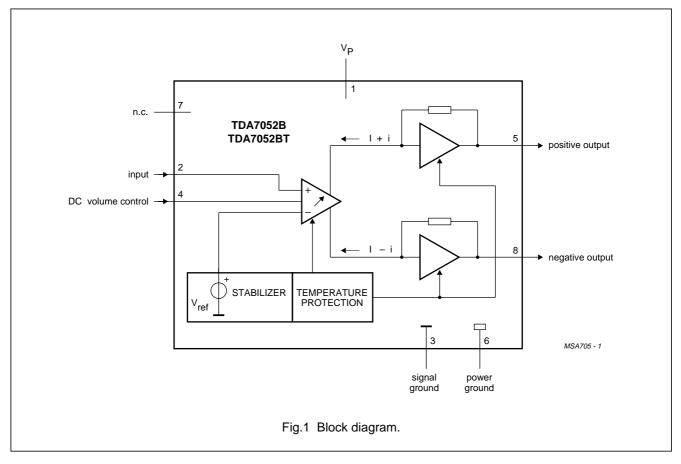
| SYMBOL              | PARAMETERS                 | CONDITIONS                               | MIN. | TYP. | MAX. | UNIT |
|---------------------|----------------------------|--|------|------|------|------|
| V <sub>P</sub>      | supply voltage             |  | 4.5  | -    | 18   | V    |
| Po                  | output power               | V <sub>P</sub> = 6 V                     |      |      |      |      |
|                     | TDA7052B                   | $R_L = 8 \Omega$                         | 0.9  | 1.0  | _    | W    |
|                     | TDA7052BT                  | $R_L = 16 \Omega$                        | 0.5  | 0.55 | _    | W    |
| G <sub>v(max)</sub> | maximum total voltage gain |  | 39.5 | 40.5 | 41.5 | dB   |
| φ                   | gain control               |  | 68   | 73.5 | -    | dB   |
| I <sub>q(tot)</sub> | total quiescent current    | V <sub>P</sub> = 6 V; R <sub>L</sub> = ∞ | _    | 9.2  | 13   | mA   |
| THD                 | total harmonic distortion  |  |      |      |      |      |
|                     | TDA7052B                   | P <sub>O</sub> = 0.5 W                   | _    | 0.3  | 1    | %    |
|                     | TDA7052BT                  | P <sub>O</sub> = 0.25 W                  | -    | 0.3  | 1    | %    |

### ORDERING INFORMATION

| TYPE      | PACKAGE |   |         |  |
|-----------|---------|---|---------|--|
| NUMBER    | NAME    | DESCRIPTION   | VERSION |  |
| TDA7052B  | DIP8    | plastic dual in-line package; 8 leads (300 mil)           | SOT97-1 |  |
| TDA7052BT | SO8     | plastic small outline package; 8 leads; body width 3.9 mm | SOT96-1 |  |

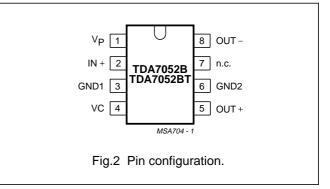
### TDA7052B

### **BLOCK DIAGRAM**



### PINNING

| SYMBOL PIN     |   | DESCRIPTION       |
|----------------|---|-------------------|
| V <sub>P</sub> | 1 | supply voltage    |
| IN+            | 2 | input             |
| GND1           | 3 | signal ground     |
| VC             | 4 | DC volume control |
| OUT+           | 5 | positive output   |
| GND2           | 6 | power ground      |
| n.c.           | 7 | not connected     |
| OUT-           | 8 | negative output   |



### FUNCTIONAL DESCRIPTION

The TDA7052B and TDA7052BT are mono BTL output amplifiers with DC volume control which have been designed for use in TV and monitors but are also suitable for use in battery-fed portable recorders and radios.

In conventional DC volume circuits the control or input stage is AC coupled to the output stage via external capacitors to keep the offset voltage low. In the TDA7052B and TDA7052BT the DC volume control stage is integrated into the input stage so that no coupling capacitors are required. With this configuration, a low offset voltage is maintained and the minimum supply voltage remains low.

The BTL principle offers the following advantages:

- · Lower peak value of the supply current
- The frequency of the ripple on the supply voltage is twice the signal frequency.

Consequently, a reduced power supply with smaller capacitors can be used which results in cost reductions. For portable applications there is a trend to decrease the supply voltage, resulting in a reduction of output power at conventional output stages. Using the BTL principle increases the output power. The maximum gain of the amplifier is fixed at 40.5 dB. The DC volume control stage has a logarithmic control characteristic. Therefore, the total gain can be controlled from 40.5 dB to -33 dB. If the DC volume control voltage falls below 0.4 V, the device will switch to the mute mode.

The amplifier is short-circuit proof to ground,  $V_P$  and across the load. Also a thermal protection circuit is implemented. If the crystal temperature rises above +150 °C the gain will be reduced, thereby reducing the output power. Special attention is given to switch-on and switch-off clicks, low HF radiation and a good overall stability.

### **Power dissipation**

Assume for the TDA7052B that V<sub>P</sub> = 6 V; R<sub>L</sub> = 8  $\Omega$ . The maximum sine wave dissipation is 0.9 W. The R<sub>th j-a</sub> of the package is 100 K/W. Therefore T<sub>amb(max)</sub> = 150 - 100 × 0.9 = 60 °C.

Assume for the TDA7052BT that V<sub>P</sub> = 6 V; R<sub>L</sub> = 16  $\Omega$ . The maximum sine wave dissipation is 0.46 W. The R<sub>th j-a</sub> of the package is 155 K/W. Therefore T<sub>amb(max)</sub> = 150 - 155 × 0.46 = 78 °C.

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL            | PARAMETER                          | CONDITIONS               | MIN. | MAX. | UNIT |
|-------------------|------------------------------------|--------------------------|------|------|------|
| V <sub>P</sub>    | supply voltage                     |                          | _    | 18   | V    |
| V <sub>2, 4</sub> | input voltage pins 2 and 4         |                          | -    | 5    | V    |
| I <sub>ORM</sub>  | repetitive peak output current     |                          | _    | 1.25 | А    |
| I <sub>OSM</sub>  | non-repetitive peak output current |                          | -    | 1.5  | A    |
| P <sub>tot</sub>  | total power dissipation            | T <sub>amb</sub> ≤ 25 °C |      |      |      |
|                   | TDA7052B                           |                          | _    | 1.25 | W    |
|                   | TDA7052BT                          |                          | _    | 0.8  | W    |
| T <sub>amb</sub>  | operating ambient temperature      |                          | -40  | +85  | °C   |
| T <sub>stg</sub>  | storage temperature                |                          | -55  | +150 | °C   |
| T <sub>vj</sub>   | virtual junction temperature       |                          | -    | +150 | °C   |
| T <sub>sc</sub>   | short-circuit time                 |                          | _    | 1    | h    |

### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER   | VALUE | UNIT |
|---------------------|---|-------|------|
| R <sub>th j-a</sub> | thermal resistance from junction to ambient in free air |       |      |
|                     | TDA7052B  | 100   | K/W  |
|                     | TDA7052BT   | 155   | K/W  |

### TDA7052B

### CHARACTERISTICS

 $V_P = 6 V$ ;  $V_{DC} = 1.4 V$ ; f = 1 kHz;  $R_L = 8 \Omega$ ;  $T_{amb} = 25 °C$ ; unless otherwise specified (see Fig.13).

| SYMBOL              | PARAMETER                         | CONDITIONS   | MIN. | TYP.        | MAX. | UNIT |
|---------------------|-----------------------------------|--|------|-------------|------|------|
| Supply              |                                   |  | 1    |             |      | 1    |
| V <sub>P</sub>      | supply voltage                    |  | 4.5  | -           | 18   | V    |
| I <sub>q(tot)</sub> | total quiescent current           | note 1; R <sub>L</sub> = ∞   | -    | 9.2         | 13   | mA   |
|                     | gain (V <sub>4</sub> ≥ 1.4 V)     |  |      |             |      |      |
| Po                  | output power                      | THD = 10%  |      |             |      |      |
|                     | TDA7052B                          |  | 0.9  | 1.0         | -    | W    |
|                     | TDA7052BT                         |  | 0.5  | 0.55        | -    | W    |
| THD                 | total harmonic distortion         |  |      |             |      |      |
|                     | TDA7052B                          | P <sub>O</sub> = 0.5 W   | _    | 0.3         | 1    | %    |
|                     | TDA7052BT                         | P <sub>O</sub> = 0.25 W  | _    | 0.3         | 1    | %    |
| G <sub>v(max)</sub> | maximum total voltage gain        |  | 39.5 | 40.5        | 41.5 | dB   |
| VI                  | input signal handling (RMS value) | $G_{v(max)} = 0 \text{ dB}; \text{ THD} < 1\%$                             | 1.0  | -           | -    | V    |
| V <sub>no</sub>     | noise output voltage (RMS value)  | note 2; f = 500 kHz  | -    | 210         | -    | μV   |
| В                   | bandwidth                         | at –1 dB   | _    | 0.02 to 300 | -    | kHz  |
| SVRR                | supply voltage ripple rejection   | note 3   | 34   | 38          | -    | dB   |
| $ \Delta V_0 $      | DC output offset voltage          | V <sub>8</sub> - V <sub>5</sub>  | _    | 0           | 200  | mV   |
| ZI                  | input impedance (pin 3)           |  | 15   | 20          | 25   | kΩ   |
| Mute posi           | tion                              |  |      |             |      |      |
| V <sub>O</sub>      | output voltage in mute position   | note 4; $V_4 = 0.4 \text{ V} \pm 30 \text{ mV}$ ;<br>$V_1 = 1.0 \text{ V}$ | -    | 30          | 40   | μV   |
| DC volum            | e control; note 5                 |  |      |             |      |      |
| φ                   | gain control                      |  | 68   | 73.5        | -    | dB   |
| I <sub>4</sub>      | control current                   | $V_4 = 0 V$  | 20   | 25          | 30   | μA   |

#### Notes

1. With a load connected to the outputs the quiescent current will increase, the maximum value of this increase being equal to the DC output offset voltage divided by R<sub>L</sub>.

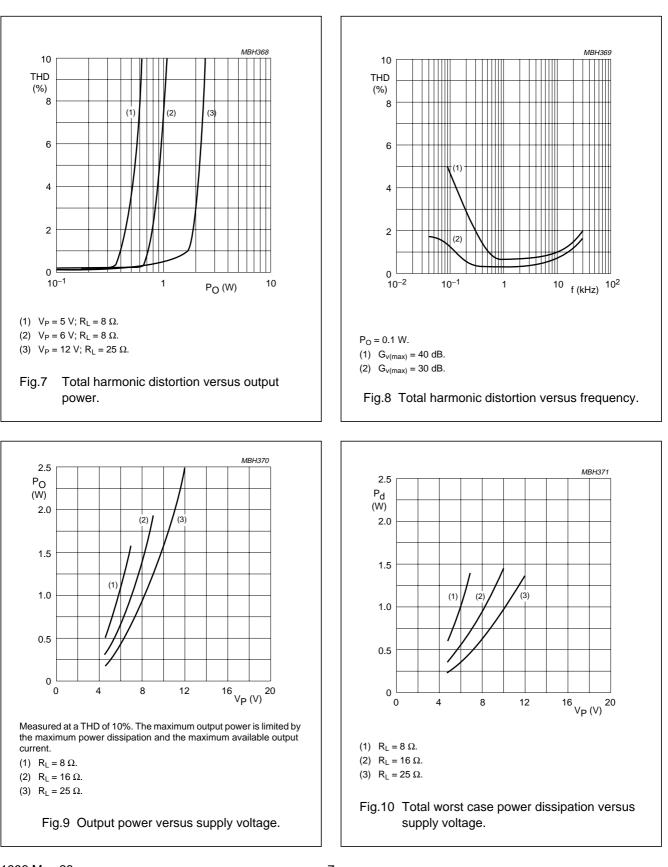
- 2. The noise output voltage (RMS value) at f = 500 kHz is measured with  $R_S = 0 \Omega$  and B = 5 kHz.
- 3. The ripple rejection is measured with  $R_S = 0 \Omega$  and f = 100 Hz to 10 kHz. The ripple voltage V<sub>R</sub> of 200 mV (RMS value) is applied to the positive supply rail.
- 4. The noise output voltage (RMS value) is measured with  $R_S = 5 \text{ k}\Omega$  unweighted.
- The DC volume control can be configured in several ways. Two possible circuits are shown in Figs 14 and 15. The circuits at the volume control pin will influence the switch-on and switch-off behaviour and the maximum voltage gain.

#### MBH372 МВН373 40 1 Gv (dB) Vno 0 (mV) 10<sup>-1</sup> -40 -80 -120 10<sup>-2</sup> 1.6 V<sub>DC</sub> (V) 0 0.4 0.8 1.2 2.0 0 0.4 0.8 1.2 1.6 2.0 $V_{DC}(V)$ Measured with $R_S = 5 \text{ k}\Omega$ unweighted. Frequency range is 22 Hz to 22 kHz. Fig.3 Gain control as a function of DC volume Fig.4 Noise output voltage as a function of DC control. volume control. МВН376 MBH367 25 20 IDC (µA) $I_P$ 15 (mA) 15 5 -5 10 -15 5 ∟ 0 -25 0.4 0.8 1.2 4 8 12 0 1.6 2.0 <sup>16</sup> V<sub>P</sub> (V) <sup>20</sup> $V_{DC}(V)$

Fig.5 Control current as a function of DC volume control.

Measured with  $R_L = \infty$ .

Fig.6 Quiescent current versus supply voltage.



-20

-30

-40

-50

-60

-70

SVRR

(dB)

**TDA7052B** 

### Mono BTL audio amplifier with DC volume control

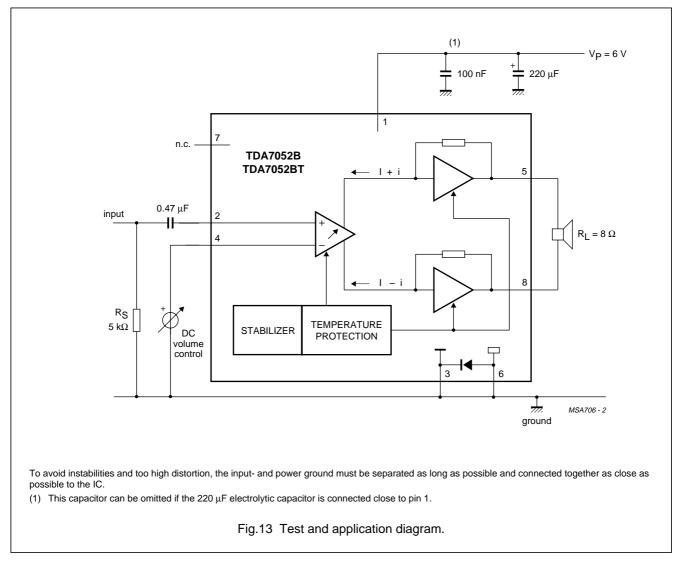
#### MBH374 MBH375 2.0 ٧I (V) 1.6 1.2 0.8 (2) ----0.4 f (kHz) <sup>102</sup> 0 10-2 10<sup>-1</sup> 10 1 0 4 8 12 $^{16}V_{P}(V)^{20}$ Measured with V<sub>R</sub> = 0.2 V. (1) $V_{DC} = 1.4 V.$ (2) $V_{DC} = 0.4 V.$ Measured at a THD of 1% and a voltage gain of 0 dB. Fig.11 Supply voltage ripple rejection versus frequency. Fig.12 Input signal handling.

### **QUALITY SPECIFICATION**

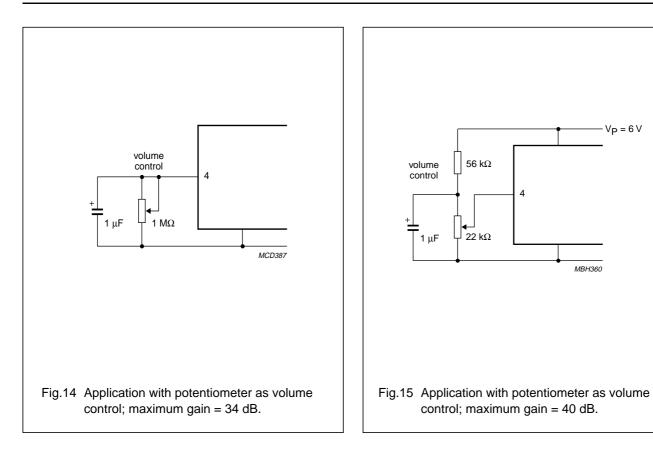
In accordance with "SNW-FQ-611E", if this type is used as an audio amplifier.

### TDA7052B

### **TEST AND APPLICATION INFORMATION**

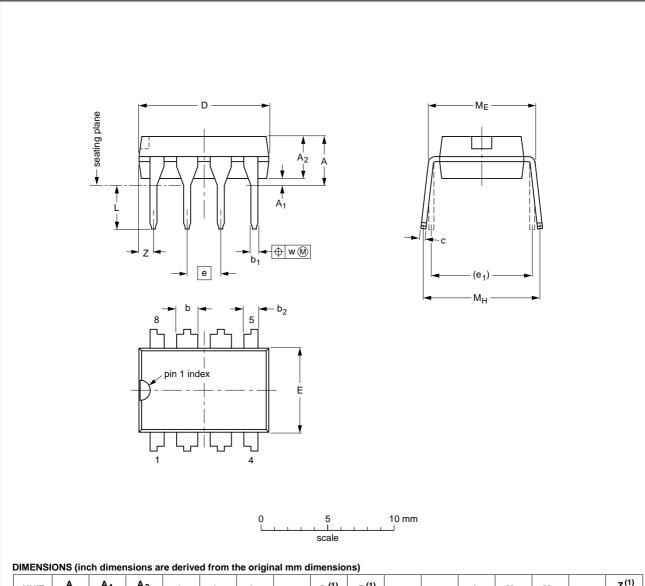


For single-end application the output peak current may not exceed 100 mA; at higher output currents the short circuit protection (MCL) will be activated.



### PACKAGE OUTLINES

### DIP8: plastic dual in-line package; 8 leads (300 mil)



| UNIT   | A<br>max. | A <sub>1</sub><br>min. | A 2<br>max. | b              | b <sub>1</sub> | b <sub>2</sub> | С              | D <sup>(1)</sup> | E <sup>(1)</sup> | е    | e <sub>1</sub> | L            | M <sub>E</sub> | M <sub>H</sub> | w     | Z <sup>(1)</sup><br>max. |
|--------|-----------|------------------------|-------------|----------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|----------------|----------------|-------|--------------------------|
| mm     | 4.2       | 0.51                   | 3.2         | 1.73<br>1.14   | 0.53<br>0.38   | 1.07<br>0.89   | 0.36<br>0.23   | 9.8<br>9.2       | 6.48<br>6.20     | 2.54 | 7.62           | 3.60<br>3.05 | 8.25<br>7.80   | 10.0<br>8.3    | 0.254 | 1.15                     |
| inches | 0.17      | 0.020                  | 0.13        | 0.068<br>0.045 | 0.021<br>0.015 | 0.042<br>0.035 | 0.014<br>0.009 | 0.39<br>0.36     | 0.26<br>0.24     | 0.10 | 0.30           | 0.14<br>0.12 | 0.32<br>0.31   | 0.39<br>0.33   | 0.01  | 0.045                    |

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE |        | REFER    | EUROPEAN ISSUE DATE |  |            |                                  |
|---------|--------|----------|---------------------|--|------------|----------------------------------|
| VERSION | IEC    | JEDEC    | EIAJ                |  | PROJECTION | 1330E DATE                       |
| SOT97-1 | 050G01 | MO-001AN |                     |  |            | <del>-92-11-17</del><br>95-02-04 |

TDA7052B

### SOT97-1

#### SO8: plastic small outline package; 8 leads; body width 3.9 mm SOT96-1 D А X = v 🕅 A Q Α2 ¥ (A<sub>3</sub> А pin 1 index $\mathsf{L}_\mathsf{p}$ 1 4 е • 🕂 w 🕅 detail X bp 2.5 5 mm 0 scale DIMENSIONS (inch dimensions are derived from the original mm dimensions) A max D<sup>(1)</sup> E<sup>(2)</sup> Z<sup>(1)</sup> θ UNIT $\mathbf{A}_1$ $A_2$ A<sub>3</sub> с е ${\sf H}_{\sf E}$ L Lp Q v w bp у 1.45 1.25 0.25 0.49 5.0 0.25 4.0 1.0 0.7 0.7 6.2 mm 1.75 0.25 1.27 1.05 0.25 0.25 0.1 5.8 0.6 0.3 0.10 0.36 4.8 3.8 0.4 0.19 8° 0<sup>0</sup> 0.010 0.057 0.019 0.0100 0.20 0.16 0.244 0.039 0.028 0.028 0.069 0.01 0.050 0.041 0.01 0.01 0.004 inches 0.049 0.228 0.004 0.014 0.0075 0.19 0.15 0.016 0.024 0.012 Notes 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included. 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included. REFERENCES OUTLINE EUROPEAN **ISSUE DATE** VERSION PROJECTION IEC JEDEC EIAJ 95-02-04 $\bigcirc$ SOT96-1 076E03S MS-012AA 97-05-22

### 1996 May 28

### SOLDERING

### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

### DIP

#### SOLDERING BY DIPPING OR BY WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg max}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than  $300 \,^{\circ}$ C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

### SO

### **REFLOW SOLDERING**

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45  $^{\circ}$ C.

#### WAVE SOLDERING

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### REPAIRING SOLDERED JOINTS

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

### TDA7052B

### DEFINITIONS

| Data sheet status   |   |  |  |  |  |
|---|---|--|--|--|--|
| Objective specification   | This data sheet contains target or goal specifications for product development.       |  |  |  |  |
| Preliminary specification   | This data sheet contains preliminary data; supplementary data may be published later. |  |  |  |  |
| Product specification   | This data sheet contains final product specifications.                                |  |  |  |  |
| Limiting values   |   |  |  |  |  |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |   |  |  |  |  |
| Application information   |   |  |  |  |  |
|   |   |  |  |  |  |

Where application information is given, it is advisory and does not form part of the specification.

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

TDA7052B

NOTES

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Argentina: see South America Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113, Tel. +61 2 805 4455, Fax. +61 2 805 4466 Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 1 60 101. Fax. +43 1 60 101 1210 Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6, 220050 MINSK, Tel. +375 172 200 733, Fax. +375 172 200 773 Belgium: see The Netherlands Brazil: see South America Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor, 51 James Bourchier Blvd., 1407 SOFIA, Tel. +359 2 689 211, Fax. +359 2 689 102 Canada: PHILIPS SEMICONDUCTORS/COMPONENTS, Tel. +1 800 234 7381, Fax. +1 708 296 8556 China/Hong Kong: 501 Hong Kong Industrial Technology Centre, 72 Tat Chee Avenue, Kowloon Tong, HONG KONG, Tel. +852 2319 7888, Fax. +852 2319 7700 Colombia: see South America Czech Republic: see Austria Denmark: Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S, Tel. +45 32 88 2636, Fax. +45 31 57 1949 Finland: Sinikalliontie 3, FIN-02630 ESPOO, Tel. +358 615 800, Fax. +358 615 80920 France: 4 Rue du Port-aux-Vins, BP317, 92156 SURESNES Cedex, Tel. +33 1 40 99 6161, Fax. +33 1 40 99 6427 Germany: Hammerbrookstraße 69, D-20097 HAMBURG, Tel. +49 40 23 52 60, Fax. +49 40 23 536 300 Greece: No. 15, 25th March Street, GR 17778 TAVROS, Tel. +30 1 4894 339/911, Fax. +30 1 4814 240 Hungary: see Austria India: Philips INDIA Ltd, Shivsagar Estate, A Block, Dr. Annie Besant Rd. Worli, MUMBAI 400 018, Tel. +91 22 4938 541, Fax. +91 22 4938 722 Indonesia: see Singapore Ireland: Newstead, Clonskeagh, DUBLIN 14, Tel. +353 1 7640 000, Fax. +353 1 7640 200 Israel: RAPAC Electronics, 7 Kehilat Saloniki St, TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 648 1007 Italy: PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3, 20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557 Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108, Tel. +81 3 3740 5130, Fax. +81 3 3740 5077 Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL, Tel. +82 2 709 1412, Fax. +82 2 709 1415 Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR, Tel. +60 3 750 5214, Fax. +60 3 757 4880 Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905, Tel. +1 800 234 7381. Fax. +1 708 296 8556 Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB, Tel. +31 40 27 83749, Fax. +31 40 27 88399 New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND, Tel. +64 9 849 4160, Fax. +64 9 849 7811 Norway: Box 1, Manglerud 0612, OSLO, Tel. +47 22 74 8000, Fax. +47 22 74 8341 Philippines: Philips Semiconductors Philippines Inc., 106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI, Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474 Poland: UI. Lukiska 10, PL 04-123 WARSZAWA, Tel. +48 22 612 2831, Fax. +48 22 612 2327 Portugal: see Spain Romania: see Italy Russia: Philips Russia, UI. Usatcheva 35A, 119048 MOSCOW, Tel. +7 095 926 5361, Fax. +7 095 564 8323 Singapore: Lorong 1, Toa Payoh, SINGAPORE 1231, Tel. +65 350 2538, Fax. +65 251 6500 Slovakia: see Austria Slovenia: see Italy South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale, 2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000, Tel. +27 11 470 5911, Fax. +27 11 470 5494 South America: Rua do Rocio 220 - 5th floor, Suite 51, CEP: 04552-903-SÃO PAULO-SP, Brazil, P.O. Box 7383 (01064-970), Tel. +55 11 821 2333, Fax. +55 11 829 1849 Spain: Balmes 22, 08007 BARCELONA Tel. +34 3 301 6312, Fax. +34 3 301 4107 Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM, Tel. +46 8 632 2000, Fax. +46 8 632 2745 Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH, Tel. +41 1 488 2686, Fax. +41 1 481 7730 Taiwan: PHILIPS TAIWAN Ltd., 23-30F, 66 Chung Hsiao West Road, Sec. 1, P.O. Box 22978, TAIPEI 100, Tel. +886 2 382 4443, Fax. +886 2 382 4444 Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd., 209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260, Tel. +66 2 745 4090, Fax. +66 2 398 0793 Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL, Tel. +90 212 279 2770, Fax. +90 212 282 6707 Ukraine: PHILIPS UKRAINE, 2A Akademika Koroleva str., Office 165, 252148 KIEV, Tel. +380 44 476 0297/1642, Fax. +380 44 476 6991 United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes, MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax, +44 181 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409, Tel. +1 800 234 7381, Fax. +1 708 296 8556 Uruguay: see South America

Vietnam: see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD, Tel. +381 11 825 344, Fax.+381 11 635 777

For all other countries apply to: Philips Semiconductors, Marketing & Sales Communications, Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

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